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Kind regards,

Team Nexperia



NXP3875Y; NXP3875G

50 V, 150 mA NPN general-purpose transistors

Rev. 1 — 12 December 2012

Product data sheet

1. Product profile

1.1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- General-purpose transistors
- Small SMD plastic packages
- Two different current gain selections
- AEC-Q101 qualified

1.3 Applications

- General-purpose switching and amplification

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|---------------------------|--|-----|-----|-----|------|
| V_{CE0} | collector-emitter voltage | open base | - | - | 50 | V |
| I_C | collector current | | - | - | 150 | mA |
| h_{FE} | DC current gain | $V_{CE} = 6\text{ V}; I_C = 2\text{ mA}$ | | | | |
| | NXP3875Y | | 120 | - | 240 | |
| | NXP3875G | | 200 | - | 400 | |

2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|-------------|--------------------|----------------|
| 1 | base | | |
| 2 | emitter | | |
| 3 | collector | | |



3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|----------|--|---------|
| | Name | Description | Version |
| NXP3875Y | TO-236AB | plastic surface-mounted package; 3 leads | SOT23 |
| NXP3875G | | | |

4. Marking

Table 4. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| NXP3875Y | *JE |
| NXP3875G | *JF |

[1] * = placeholder for manufacturing site code.

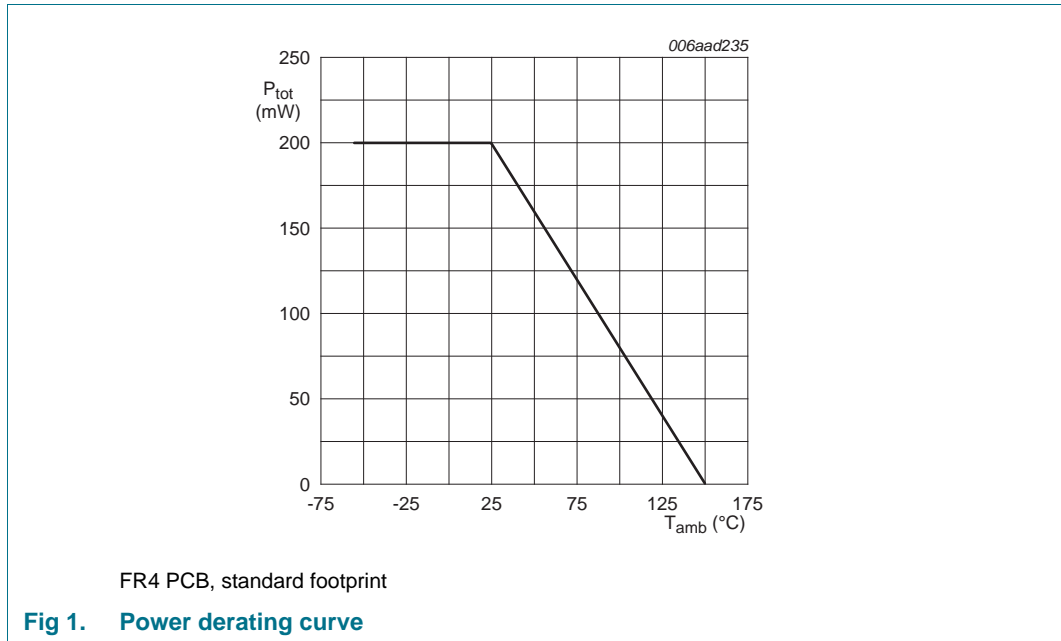
5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|---------------------------|----------------------------------|------------------|------|------|
| V_{CBO} | collector-base voltage | open emitter | - | 60 | V |
| V_{CEO} | collector-emitter voltage | open base | - | 50 | V |
| V_{EBO} | emitter-base voltage | open collector | - | 5 | V |
| I_C | collector current | | - | 150 | mA |
| I_{CM} | peak collector current | single pulse; $t_p \leq 1$ ms | - | 200 | mA |
| I_B | base current | | | 30 | mA |
| I_{BM} | peak base current | single pulse; $t_p \leq 1$ ms | - | 100 | mA |
| P_{tot} | total power dissipation | $T_{amb} \leq 25$ °C | ^[1] - | 200 | mW |
| T_j | junction temperature | | - | 150 | °C |
| T_{amb} | ambient temperature | | -65 | +150 | °C |
| T_{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

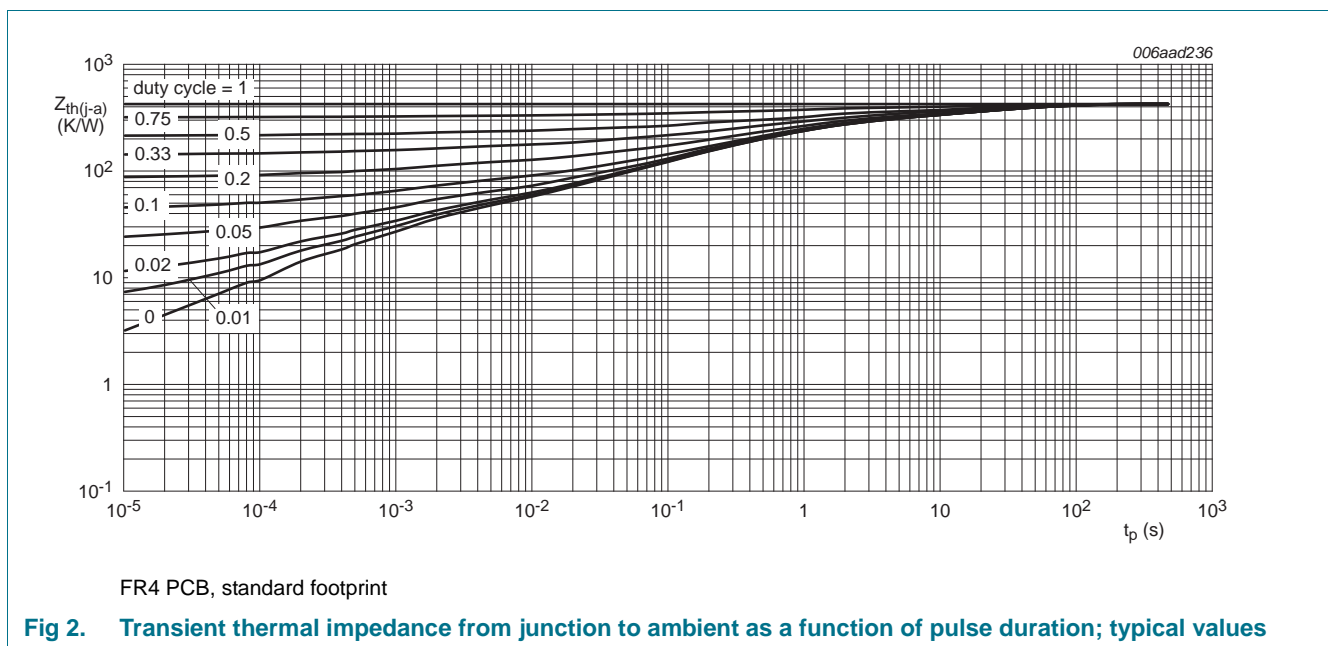


6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------|---|-------------|-------|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] - | - | 625 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

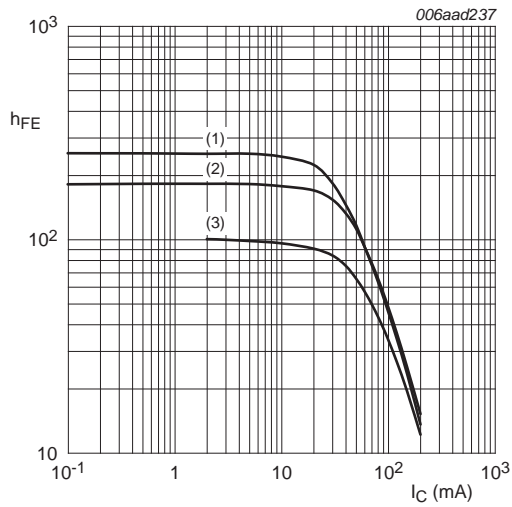


7. Characteristics

Table 7. Characteristics

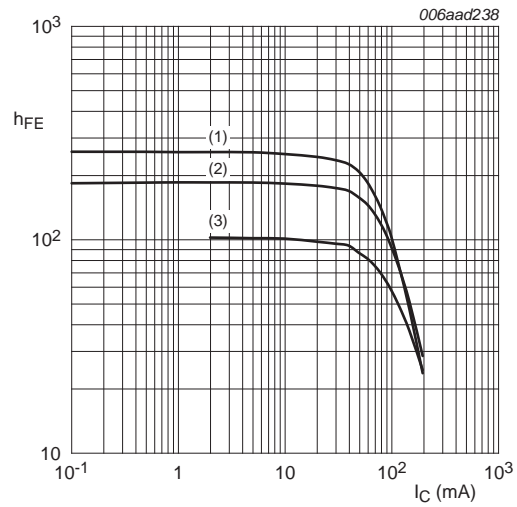
$T_{amb} = 25\text{ °C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|-------------|--------------------------------------|--|----------|-----|-----|---------------|--|
| I_{CBO} | collector-base cut-off current | $V_{CB} = 60\text{ V}; I_E = 0\text{ A}$ | - | - | 100 | nA | |
| | | $V_{CB} = 60\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ °C}$ | - | - | 5 | μA | |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = 5\text{ V}; I_C = 0\text{ A}$ | - | - | 100 | nA | |
| h_{FE} | DC current gain | $V_{CE} = 6\text{ V}; I_C = 2\text{ mA}$ | | | | | |
| | | | NXP3875Y | 120 | - | 240 | |
| | | | NXP3875G | 200 | - | 400 | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 100\text{ mA}; I_B = 10\text{ mA}$ | - | - | 250 | mV | |
| V_{BEsat} | base-emitter saturation voltage | $I_C = 100\text{ mA}; I_B = 10\text{ mA}$ | - | - | 1 | V | |
| f_T | transition frequency | $V_{CE} = 10\text{ V}; I_C = 1\text{ mA}; f = 100\text{ MHz}$ | 80 | - | - | MHz | |
| C_c | collector capacitance | $V_{CB} = 10\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$ | - | - | 3.5 | pF | |
| NF | noise figure | $I_C = 0.1\text{ mA}; V_{CE} = 6\text{ V}; R_S = 10\text{ k}\Omega; f = 1\text{ kHz};$ | - | - | 10 | dB | |



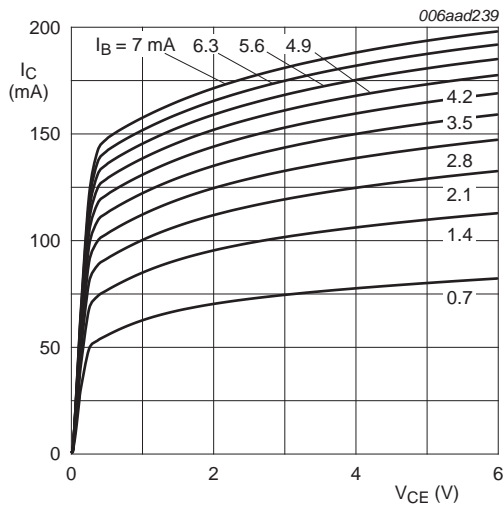
$V_{CE} = 1 \text{ V}$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -55 \text{ }^\circ\text{C}$

Fig 3. NXP3875Y: DC current gain as a function of collector current; typical values



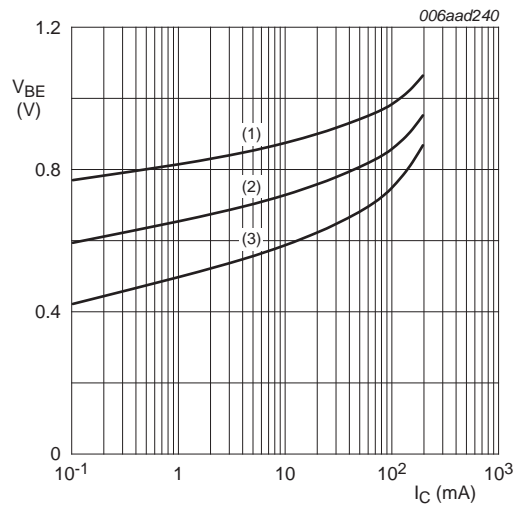
$V_{CE} = 6 \text{ V}$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -55 \text{ }^\circ\text{C}$

Fig 4. NXP3875Y: DC current gain as a function of collector current; typical values



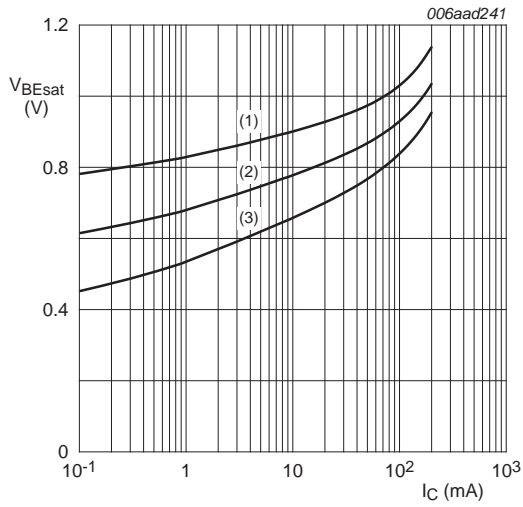
$T_{amb} = 25 \text{ }^\circ\text{C}$

Fig 5. NXP3875Y: Collector current as a function of collector-emitter voltage; typical values



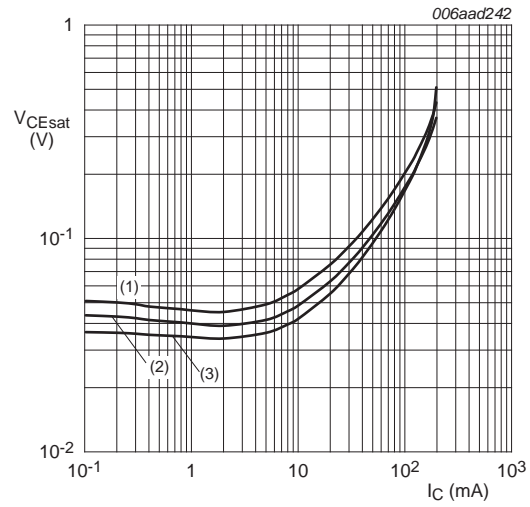
$V_{CE} = 6 \text{ V}$
 (1) $T_{amb} = -55 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig 6. NXP3875Y: Base-emitter voltage as a function of collector current; typical values



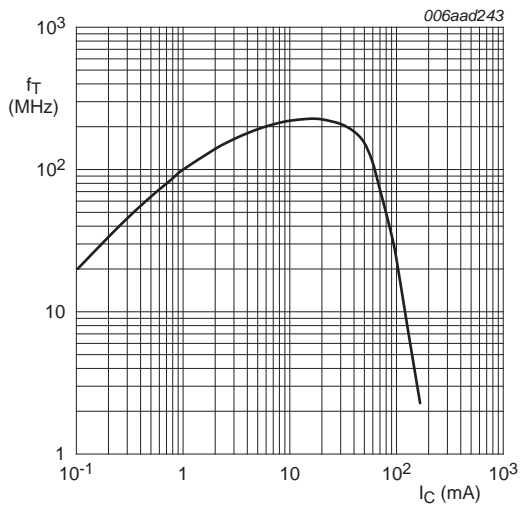
$I_C/I_B = 10$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig 7. NXP3875Y: Base-emitter saturation voltage as a function of collector current; typical values



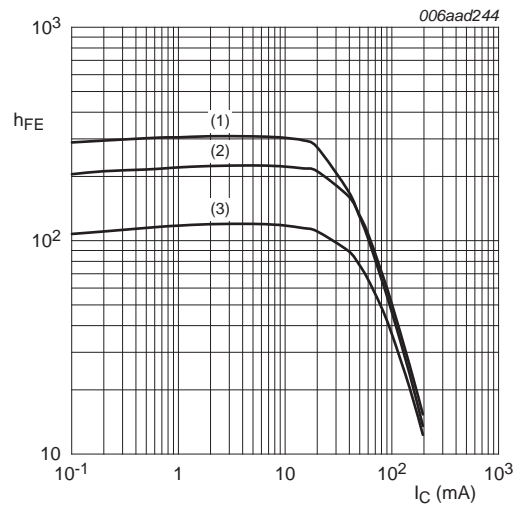
$I_C/I_B = 10$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig 8. NXP3875Y: Collector-emitter saturation voltage as a function of collector current; typical values



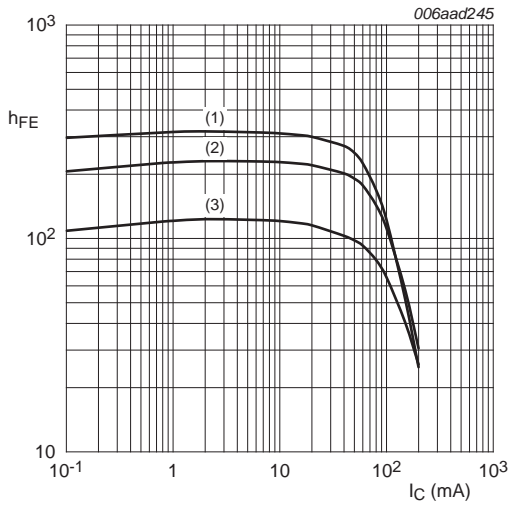
$V_{CE} = 10\text{ V}; T_{amb} = 25\text{ °C}$

Fig 9. NXP3875Y: Transition frequency as a function of collector current; typical values



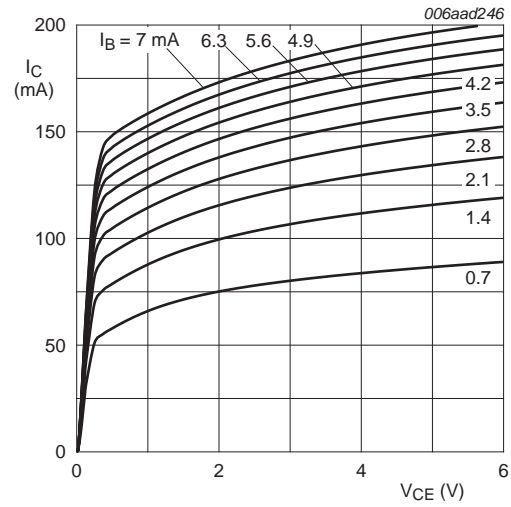
$V_{CE} = 1\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig 10. NXP3875G: DC current gain as a function of collector current; typical values



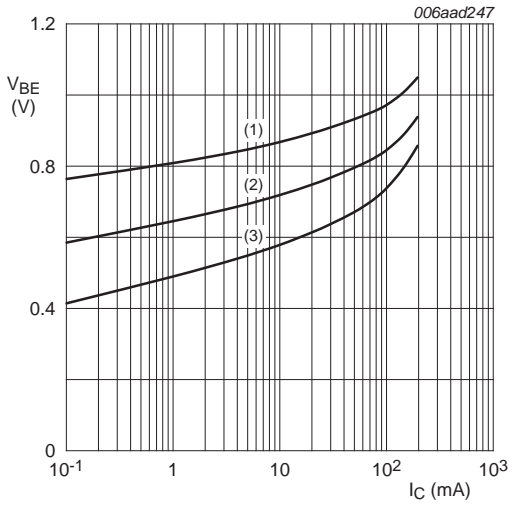
$V_{CE} = 6\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig 11. NXP3875G: DC current gain as a function of collector current; typical values



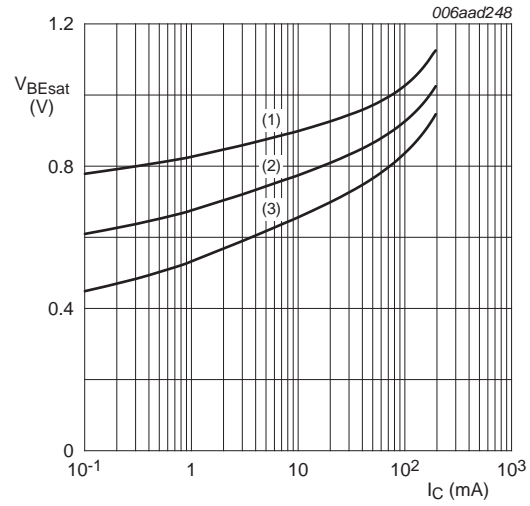
$T_{amb} = 25\text{ °C}$

Fig 12. NXP3875G: Collector current as a function of collector-emitter voltage; typical values



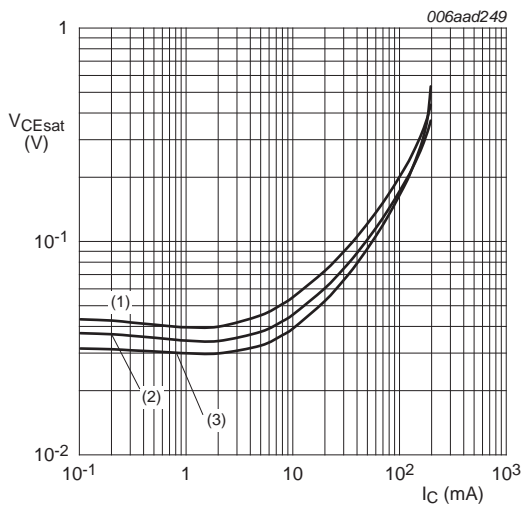
$V_{CE} = 6\text{ V}$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig 13. NXP3875G: Base-emitter voltage as a function of collector current; typical values



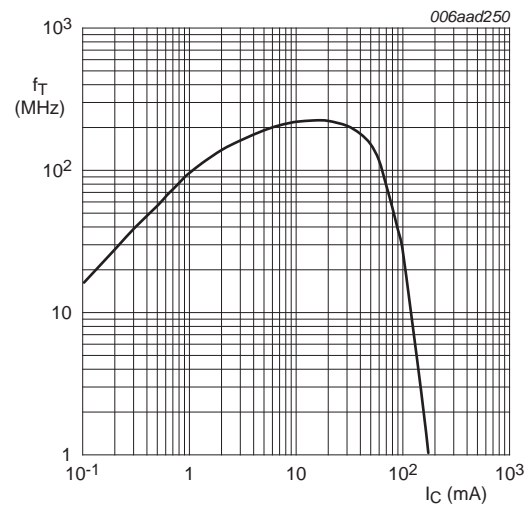
$I_C/I_B = 10$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig 14. NXP3875G: Base-emitter saturation voltage as a function of collector current; typical values



- $I_C/I_B = 10$
- (1) $T_{amb} = 100\text{ °C}$
 - (2) $T_{amb} = 25\text{ °C}$
 - (3) $T_{amb} = -55\text{ °C}$

Fig 15. NXP3875G: Collector-emitter saturation voltage as a function of collector current; typical values



$V_{CE} = 10\text{ V}; T_{amb} = 25\text{ °C}$

Fig 16. NXP3875G: Transition frequency as a function of collector current; typical values

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

11. Soldering

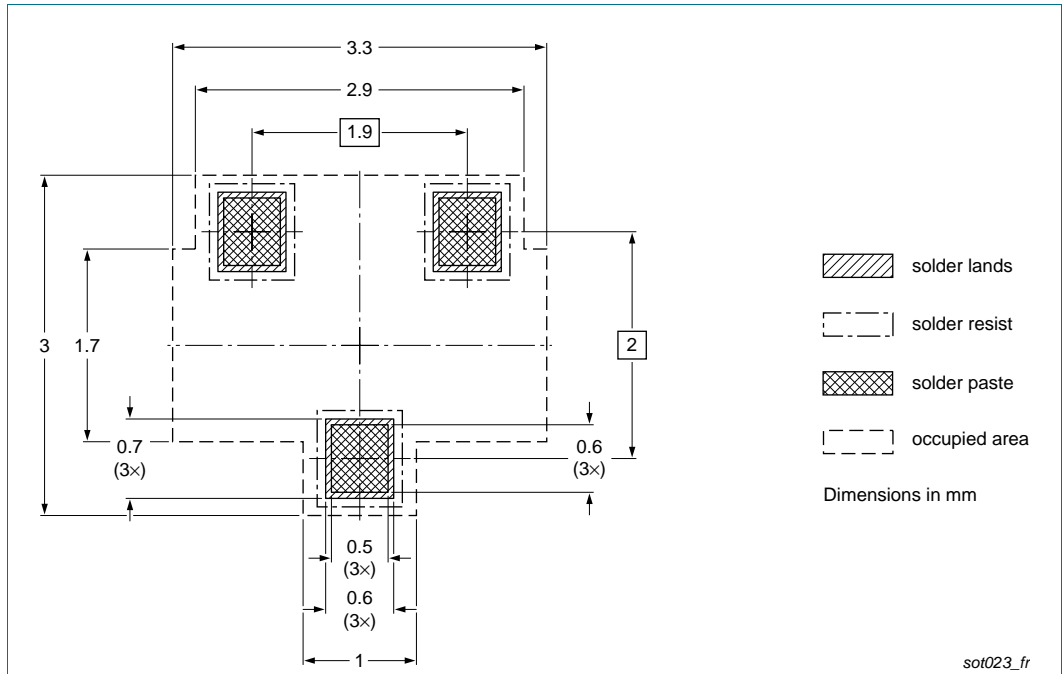


Fig 18. Reflow soldering footprint SOT23 (TO-236AB)

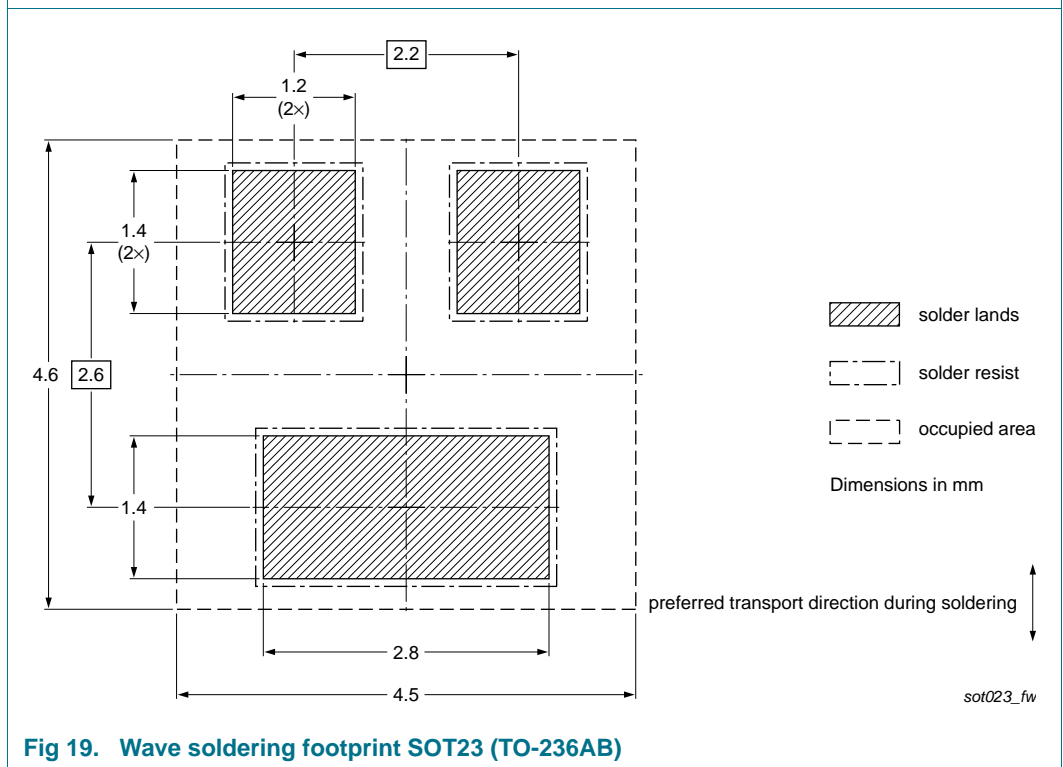


Fig 19. Wave soldering footprint SOT23 (TO-236AB)

12. Revision history

Table 9. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------------|--------------|--------------------|---------------|------------|
| NXP3875Y_NXP3875G v.1 | 20121212 | Product data sheet | - | - |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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[2] The term 'short data sheet' is explained in section "Definitions".

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